Plan for experimental validation

The manufacture of materials, device fabrication, characterization, and performance analysis would be the usual steps involved in experimentally validating the performance of Al/FTO/SnS₂/PbS/SnS/Ni solar cell. The all-inclusive plan that follows is provided:

A. Materials Synthesis and Preparation

- Substrate (FTO) Preparation:
 - **Cleaning:** The initial steps are glass substrates of tin oxide (FTO) doped with fluorine. Before being dried with nitrogen, the substrates are cleaned using a series of sonication techniques in detergent, deionized water, acetone, and isopropanol.
 - **Etching:** If required, use a zinc powder and HCl solution to etch the FTO layer, defining the solar cell's active area.
- SnS₂ Layer Deposition:
 - Chemical Bath Deposition (CBD): Apply CBD to the FTO substrate to form a SnS₂ thin film. The bath typically contains a mixture of cadmium salt (such Cd(NO₃)₂), thiourea, ammonia, and deionized water.
 - Annealing: To increase adhesion and crystallinity, anneal the SnS₂ layer at about 300°C after deposition.
- Absorber Layer (PbS) Deposition:
 - Synthesis of Absorber Materials: Utilize solid-state or solution-based techniques to create PbS powder. X-ray diffraction (XRD) and scanning electron microscopy (SEM) are used to characterize the materials.
 - Deposition: To ensure regulated thickness and homogeneity, install the dual absorber layer using methods such as spin coating, heat evaporation, or sputtering. Depending on the planned device design, this layer may be a mixed deposition or a sequential deposition of PbS.

 Annealing: Crystallinity can be enhanced by post-deposition annealing in an inert environment at the proper temperatures, which are typically between 100 and 300°C.

• SnS Layer Deposition:

- Thermal Evaporation/Sputtering: As an HTL, cover the dual absorber with a thin coating of SnS. For efficient hole extraction, the thickness should be tuned, typically between 20 and 50 nm.
- Annealing: To maximize the SnS characteristics, a mild annealing procedure may be required.

• Ni Electrode Deposition:

• Thermal Evaporation/Sputtering: To create a top electrode, deposit the Ni contact layer using heat evaporation or sputtering. Gain a solid understanding of the underlying SnS layer.

• Al Contact Deposition:

• **Thermal Evaporation/Sputtering:** Lastly, if required, affix an Al layer as a back contact to the FTO's rear side. Depending on the design, this stage may be completed after the front layers are deposited.

B. Device Fabrication

- Layer Assembly: The layers should be assembled as follows: Al/FTO/SnS₂/PbS/SnS/Ni. Ensure that each layer is deposited under closely watched conditions to prevent contamination and maintain interface quality.
- Encapsulation: Cover the thing to keep moisture and air from causing it to decay.

C. Characterization

- Structural Characterization:
 - **X-ray Diffraction (XRD):** To determine which crystallographic phases the materials in question are situated in.

 Scanning Electron Microscopy (SEM) and Energy-Dispersive X-ray Spectroscopy (EDS): To investigate the layer's thickness, chemistry, and surface shape.

• Optical Characterization:

- UV-Vis Spectroscopy: To see the absorption spectra and figure out the absorber layers' bandgap.
- **Photoluminescence (PL) Spectroscopy:** To evaluate the absorber layers' quality and locate any flaws or recombination sites.

• Electrical Characterization:

- Current-Voltage (J-V) Measurements: To determine the PV parameters, including V_{OC} , J_{SC} , FF, and PCE.
- External Quantum Efficiency (EQE): To quantify the photoreaction of the solar cell that is dependent on wavelength.
- Impedance Spectroscopy: To look into charge transport routes and recombination.

D. Performance Analysis

- **Stability Testing:** Analyze the stability of the solar cells in various lighting scenarios, temperature fluctuations, and meteorological factors (such as humidity).
- **Comparison with Theoretical Predictions:** Verify the device's behavior and effectiveness by comparing the experimental findings with theoretical models.

E. Optimization

- **Parameter Tuning:** Based on the first results, modify the annealing temperatures, deposition circumstances, and layer thicknesses to enhance the device's performance.
- **Repeat and Validate:** To guarantee uniformity and reproducibility of the results, create a large number of devices.

This method covers material production, device construction, characterization, and performance analysis, offering a thorough method for experimentally verifying the Al/FTO/SnS₂/PbS/SnS/Ni solar cell's performance.